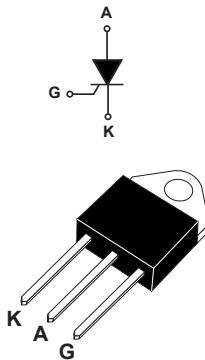


40 A, 1200 V standard SCR


TOP3 Isolated

Features

- Max. Repetitive Blocking Voltage = V_{DRM} , $V_{RRM} = 1200$ V
- I_{GT} maximum = 50 mA
- High static and dynamic commutation:
 - $dI/dt = 100$ A/ μ s
 - $dV/dt = 2000$ V/ μ s
- ECOPACK®2 component (RoHS and HF compliance)
- Complies with UL 1557 standard (File ref : E81734)

Applications

- Solar / Wind renewable energy inverters and rectifiers
- Solid state relay (SSR)
- Uninterruptible power supply (UPS)
- Industrial SMPS
- Bypass
- AC DC inrush current limiter (ICL)
- Battery charger
- AC DC voltage controlled rectifier
- Industrial welding systems
- Off board automotive battery charger
- Soft starter
- Heating systems

Product status	
TN4050-12PI	
Product summary	
Order code	TN4050-12PI
Package	TOP3 isolated
$I_T(\text{RMS})$	40 A
V_{DRM}/V_{RRM}	1200 V
I_{GT}	50 mA

Description

The **TN4050-12PI** SCR is suitable in industrial applications where high immunity is required with a lower gate current and ceramic isolated tab, UL1557 certified rated at 2.5 kV RMS and UL94-V0 resin compliance.

Available in through-hole high power package TOP3 isolated tab.

1 Characteristics

Table 1. Absolute maximum ratings (limiting values)

Symbol	Parameter			Value	Unit
$I_{T(RMS)}$	On-state RMS current (180 ° conduction angle)	$T_c = 82.5 \text{ }^\circ\text{C}$	$t_p = 8.3 \text{ ms}$	40	A
$I_{T(AV)}$				25	
I_{TSM}	Non repetitive surge peak on-state current (T_j initial = 25 °C)	$t_p = 10 \text{ ms}$	420	A	
I^2t			400		
dI/dt	Critical rate of rise of on-state current $I_G = 100 \text{ mA}, dI_G/dt = 1 \text{ A}/\mu\text{s}$	$f = 60 \text{ Hz}$	$T_j = 125 \text{ }^\circ\text{C}$	100	A/ μ s
I_{GM}	Maximum peak positive gate current	$t_p = 20 \mu\text{s}$	$T_j = 125 \text{ }^\circ\text{C}$	8	A
V_{GM}	Maximum peak positive gate voltage			5	V
$P_{G(AV)}$	Average gate power dissipation	$T_j = 125 \text{ }^\circ\text{C}$	1	W	
V_{RGM}	Maximum peak reverse gate voltage				V
T_{stg}	Storage junction temperature range	$T_j = 125 \text{ }^\circ\text{C}$	-40 to +150	°C	
T_j	Operating junction temperature range				

Table 2. Electrical characteristics ($T_j = 25 \text{ }^\circ\text{C}$ unless otherwise specified)

Symbol	Test conditions			Value	Unit
I_{GT}	$V_D = 12 \text{ V}, R_L = 33 \Omega$		$T_j = 125 \text{ }^\circ\text{C}$	Min.	10
V_{GT}				Max.	50
V_{GD}	$V_D = V_{DRM}, R_L = 3.3 \text{ k}\Omega$			Max.	1.5
I_H	$I_T = 500 \text{ mA}$, gate open			Max.	100
I_L	$I_G = 1.2 \times I_{GT}$			Max.	130
dV/dt	$V_D = 67\% V_{DRM}$, gate open		$T_j = 125 \text{ }^\circ\text{C}$	Min.	2
t_{gt}	$I_T = 40 \text{ A}, V_D = V_{DRM}, I_G = 200 \text{ mA}, (dI_G/dt) \text{ max} = 0.2 \text{ A}/\mu\text{s}$			Typ.	2
t_q	$I_{TM} = 40 \text{ A}, V_D = 800 \text{ V}, dI_{TM}/dt = 30 \text{ A}/\mu\text{s}, V_R = 75 \text{ V}, dV_D/dt = 20 \text{ V}/\mu\text{s}$		$T_j = 125 \text{ }^\circ\text{C}$	Typ.	100

Table 3. Static characteristics

Symbol	Test conditions			Value	Unit
V_{TM}	$I_{TM} = 80 \text{ A}, t_p = 380 \mu\text{s}$	$T_j = 25 \text{ }^\circ\text{C}$	$T_j = 125 \text{ }^\circ\text{C}$	Max.	1.75
V_{TO}				Max.	0.9
R_D	$V_{DRM} = V_{RRM} = 1200 \text{ V}$	$T_j = 125 \text{ }^\circ\text{C}$	Max.	9.8	mΩ
I_{DRM}, I_{RRM}			$T_j = 25 \text{ }^\circ\text{C}$	Max.	10
				Max.	5
			$T_j = 125 \text{ }^\circ\text{C}$		mA

Table 4. Thermal parameters

Symbol	Parameter	Value	Unit
$R_{th(j-c)}$	Junction to case (DC)	1.1	°C/W
$R_{th(j-a)}$	Junction to ambient (DC)	50	

1.1 Characteristics curves

Figure 1. Maximum average power dissipation versus average on-state current

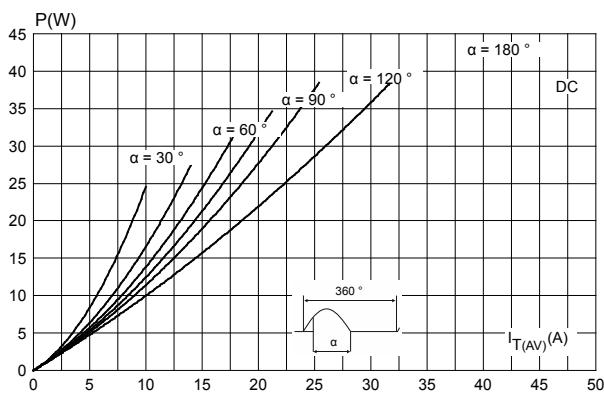


Figure 2. Average and DC on-state current versus case temperature

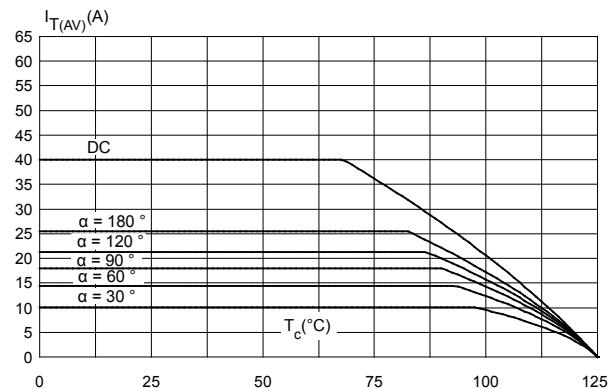


Figure 3. On-state characteristics (maximum values)

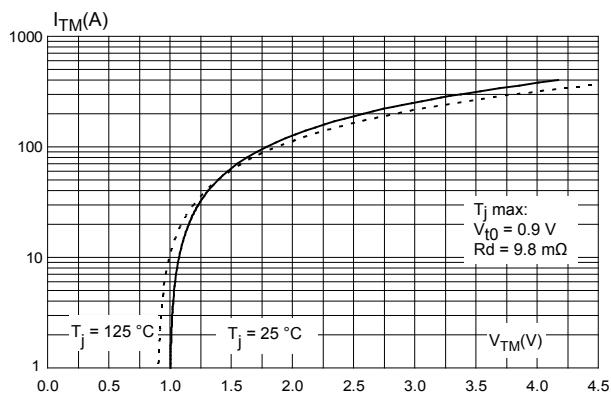


Figure 4. Average and D.C. on-state current versus ambient temperature

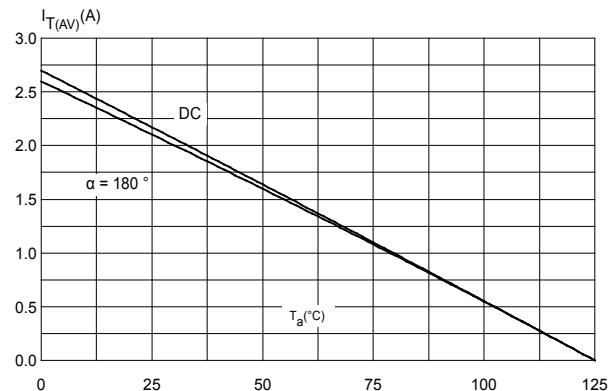


Figure 5. Relative variation of thermal impedance junction to case and junction to ambient versus pulse duration

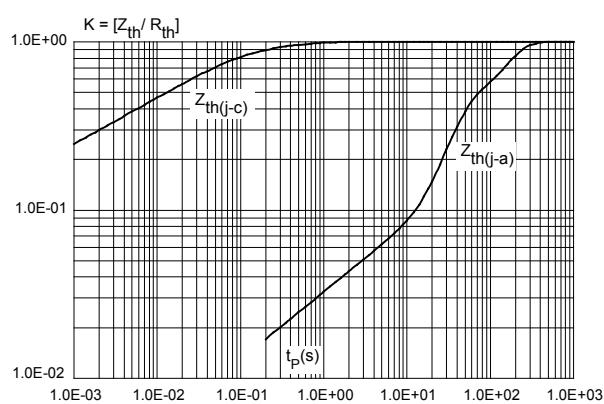


Figure 6. Surge peak on-state current versus number of cycles

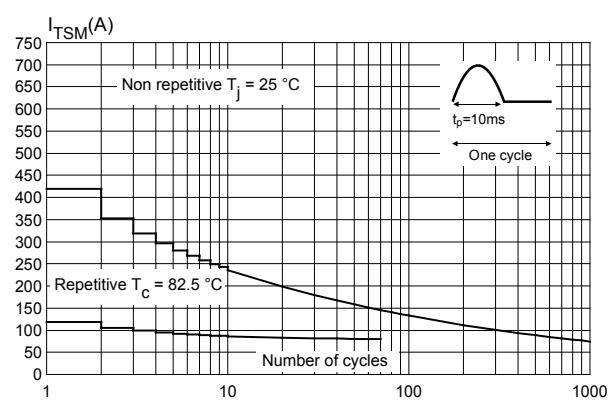
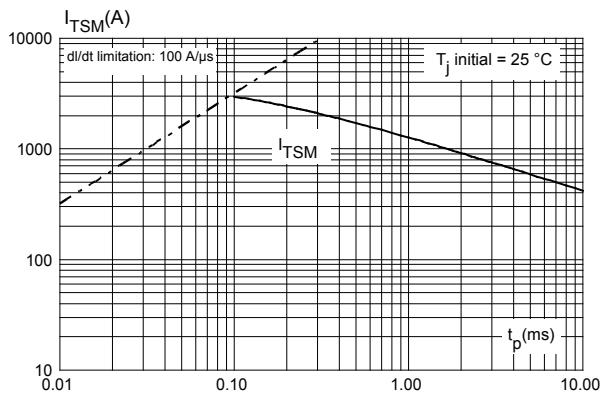
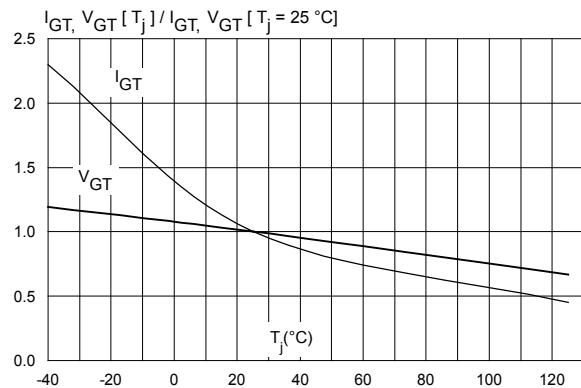
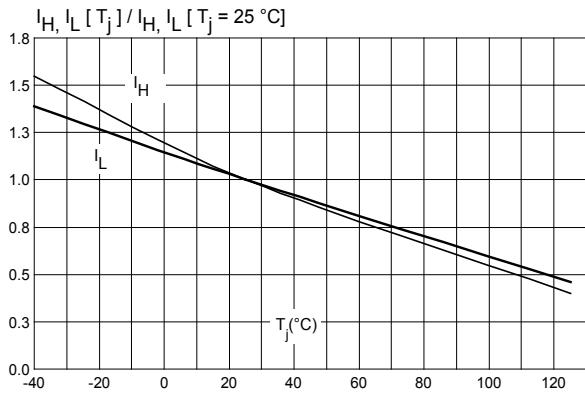
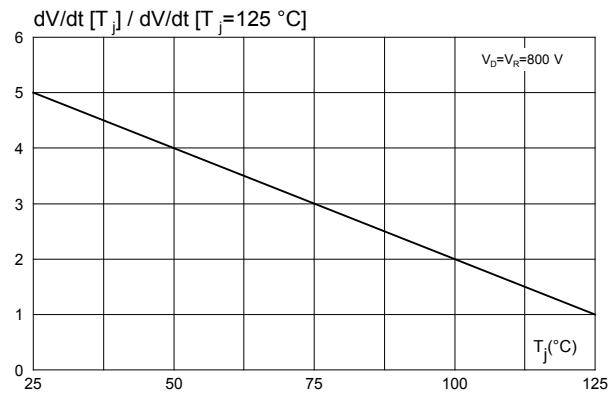
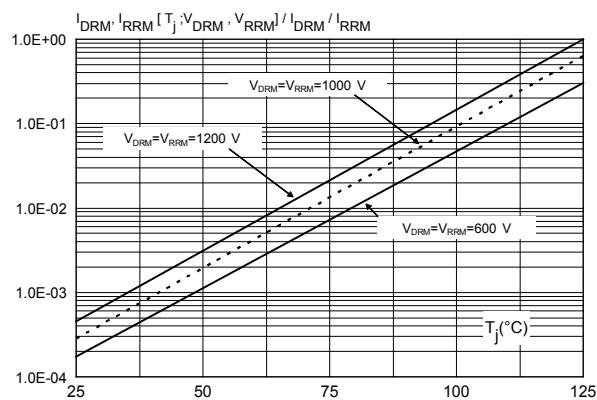


Figure 7. Non repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 10 \text{ ms}$ **Figure 8.** Relative variation of gate trigger current and gate trigger voltage versus junction temperature (typical value)**Figure 9.** Relative variation of holding and latching current versus junction temperature (typical value)**Figure 10.** Relative variation of static dV/dt immunity versus junction temperature**Figure 11.** Relative variation of leakage current versus junction temperature for different values of blocking voltage (typical values)

2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of **ECOPACK®** packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

2.1 TOP3 Isolated package information

- **ECOPACK®** (Lead-free plating and Halogen free package compliance)
- Lead-free package leads finishing
- Halogen-free molding compound resin meets UL94 standard level V0
- Recommended torque: 1.05 N·m (max. torque: 1.2 N·m)

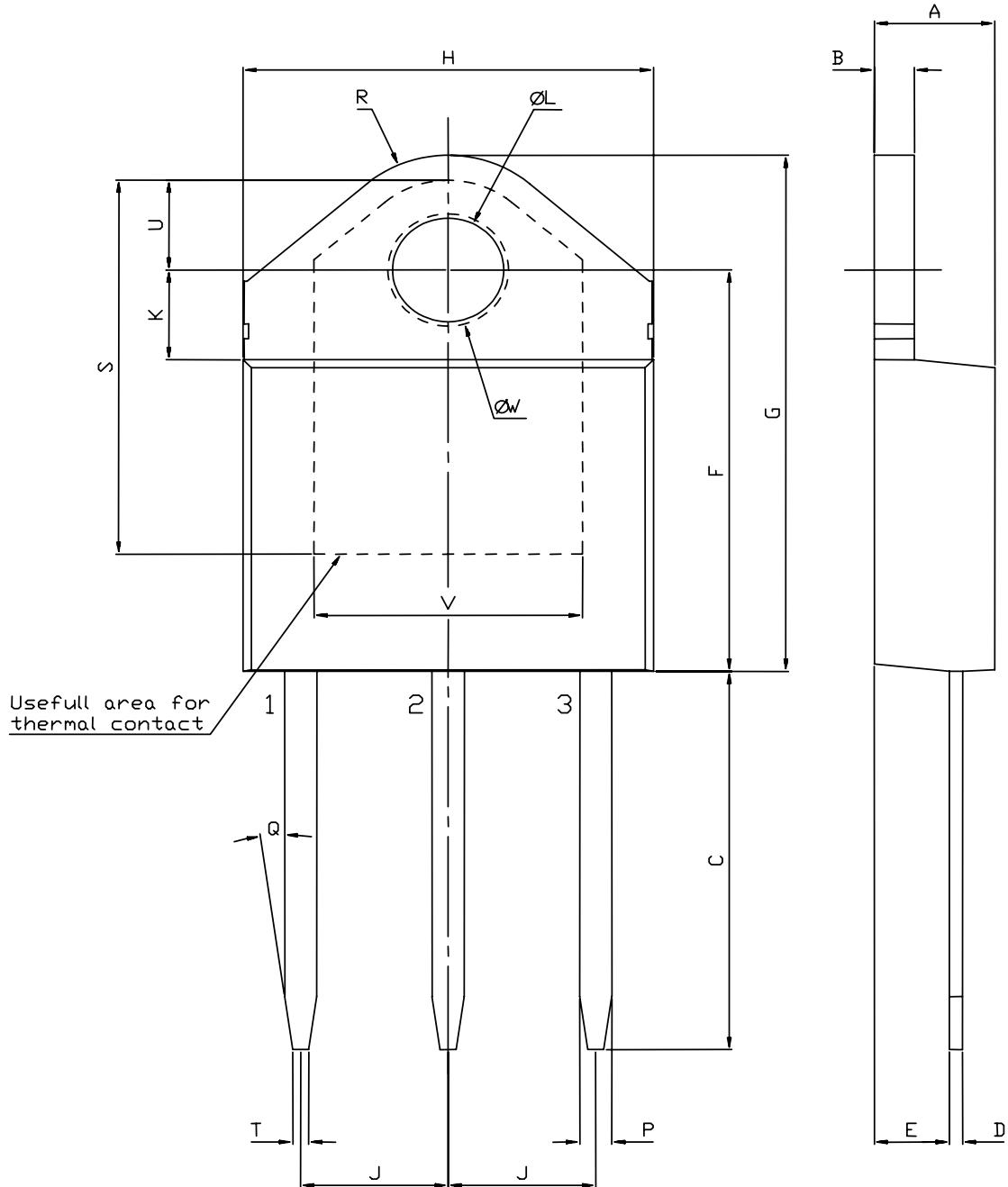
Figure 12. TOP3 Isolated package outline

Table 5. TOP3 Isolated mechanical data

Ref.	Dimensions					
	mm			Inches ⁽¹⁾		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.40		4.60	0.1732		0.1811
B	1.45		1.55	0.0571		0.0610
C	14.35		15.60	0.5650		0.6142
D	0.50		0.70	0.0197		0.0276
E	2.70		2.90	0.1063		0.1142
F	15.80		16.50	0.6220		0.6496
G	20.40		21.10	0.8031		0.8307
H	15.10		15.50	0.5945		0.6102
J	5.40		5.65	0.2126		0.2224
K	3.40		3.65	0.1339		0.1437
L	4.08		4.17	0.1606		0.1642
M	1.20		1.40	0.0472		0.0551
R		4.60			0.1811	

1. Inches given for reference only

3 Ordering information

Figure 13. Ordering information scheme

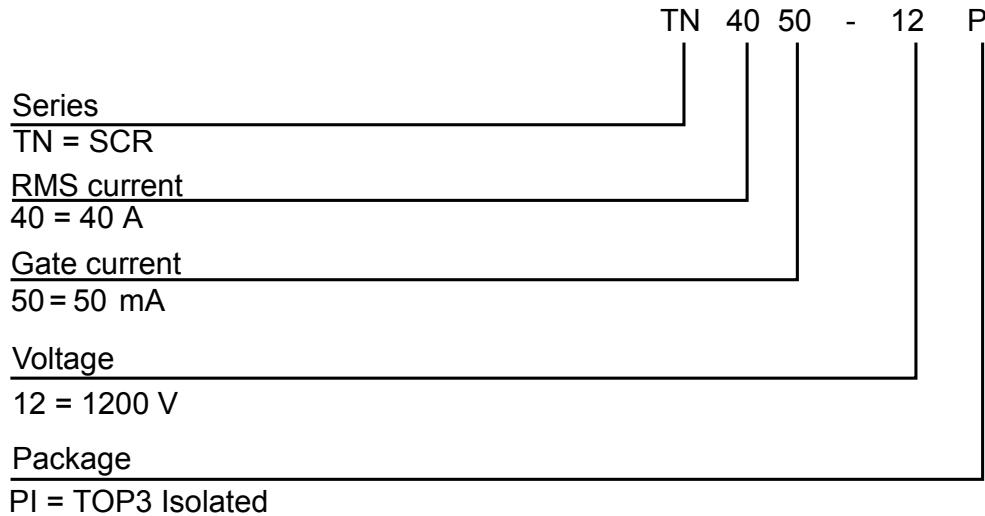


Table 6. Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
TN4050-12PI	TN405012PI	TOP3 Isolated	4.48 g	30	Tube

Revision history

Table 7. Document revision history

Date	Revision	Changes
18-Feb-2019	1	Initial release.

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